

SPICE Device Model SUP57N20-33

Vishay Siliconix

N-Channel 200-V (D-S) 175°C MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

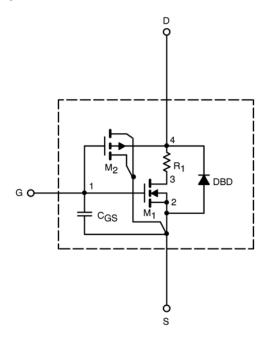
- · Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static			-		
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS} , I_D = 250 μ A	3.2		V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} > 5 \text{ V}, V_{GS} = 10 \text{ V}$	185		Α
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = 10 V, I_{D} = 30 A	0.027	0.023	Ω
		V_{GS} = 10 V, I_{D} = 30 A, T_{J} = 125°C	0.047		
		V_{GS} = 10 V, I_{D} = 30 A, T_{J} = 175°C	0.058		
Forward Transconductance ^a	9 _{fs}	V_{DS} = 15 V, I_{D} = 30 A	91		S
Forward Voltage ^a	V_{SD}	$I_{S} = 65 \text{ A}, V_{GS} = 0 \text{ V}$	0.92	1	V
Dynamic ^b			-		
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz	4857	5100	pF
Output Capacitance	C _{oss}		533	480	
Reverse Transfer Capacitance	C _{rss}		209	210	
Total Gate Charge ^c	Q_g	V _{DS} = 100 V, V _{GS} = 10 V, I _D = 85 A	93	90	nC
Gate-Source Charge ^c	Q_{gs}		23	23	
Gate-Drain Charge ^c	Q_{gd}		34	34	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 100 \text{ V}, \text{ R}_L = 1.5 \Omega$ $I_D \cong 65 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_G = 2.5 \Omega$ $I_F = 50 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	83	24	ns
Rise Time ^c	t _r		93	220	
Turn-Off Delay Time ^c	$t_{d(off)}$		104	45	
Fall Time ^c	t _f		113	200	
Reverse Recovery Time	t _{rr}		60	75	

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

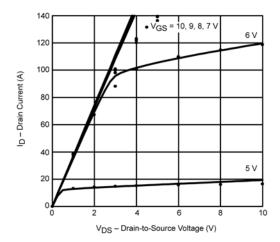
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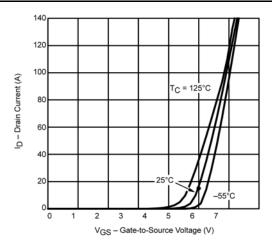


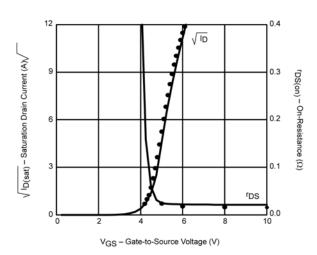
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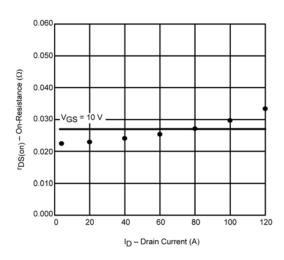
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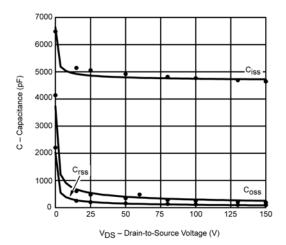
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

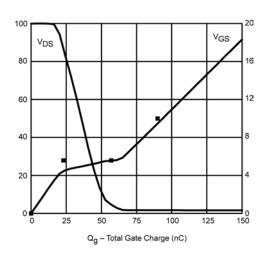












Note: Dots and squares represent measured data.



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